





	°C					
	°C					
	°C					
	°C					
	°C					
	°C					
	°C					
	°C					



			±		

FIG 4 Power dissipation characteristics
(per thyristor or diode)

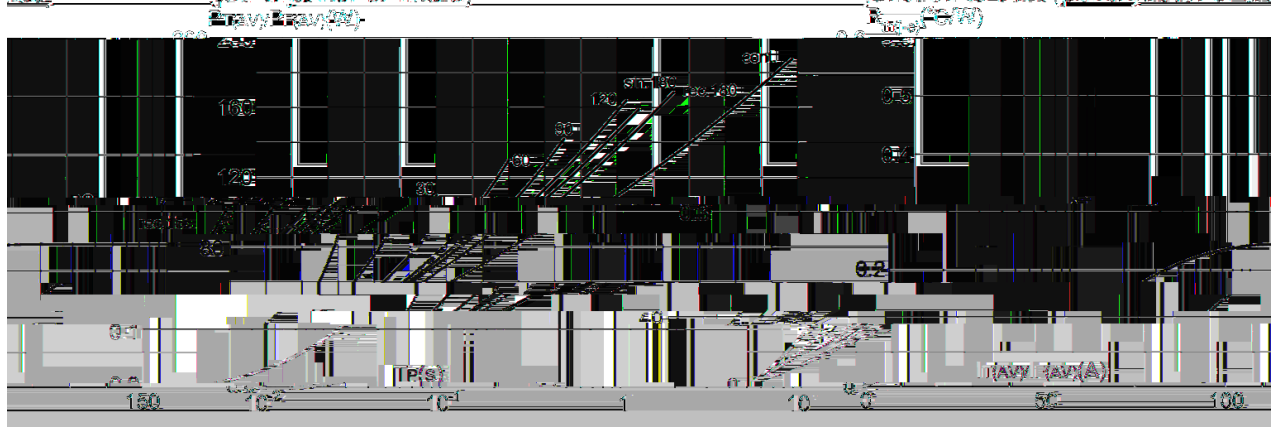


FIG 5 Maximum junction to case temperature
junction to case(per thyristor or diode)

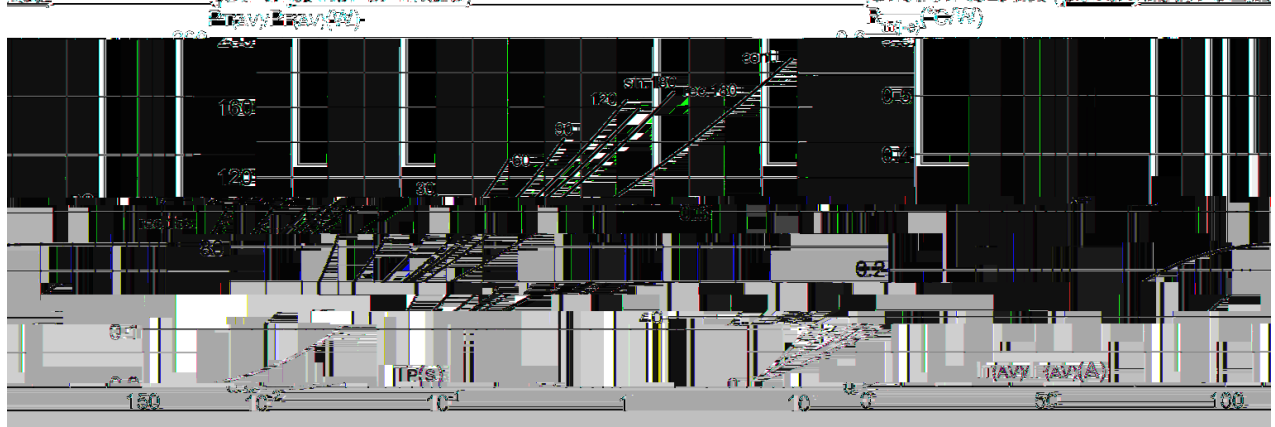


FIG 6 Forward characteristics
(per thyristor or diode)

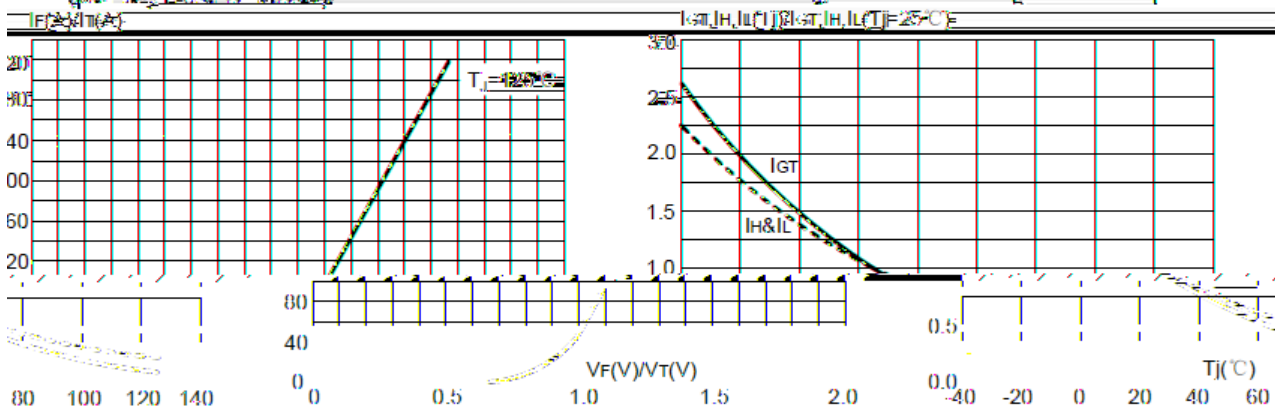


FIG 7 Relative variation of gate trigger current
current and gate trigger voltage

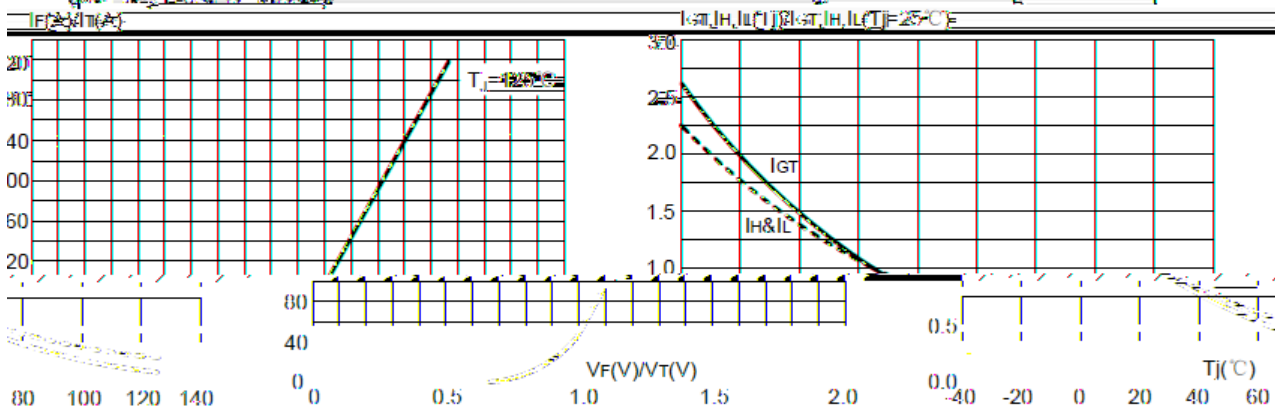


FIG 5 Gate trigger characteristics

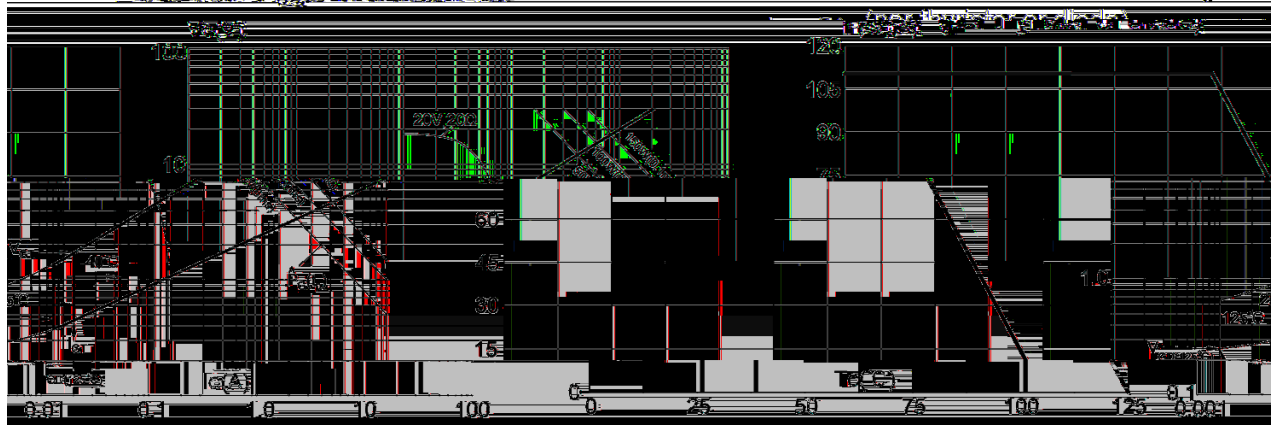


FIG 6 Forward current vs. case temperature

